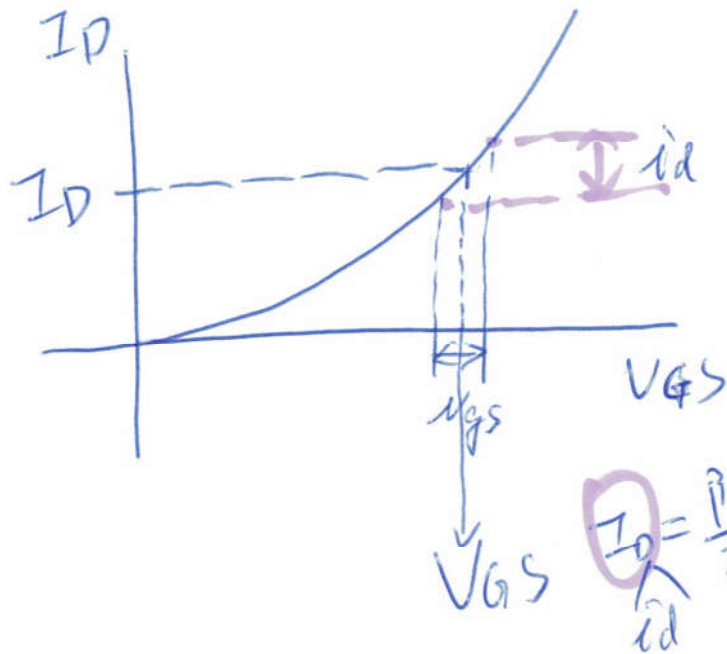
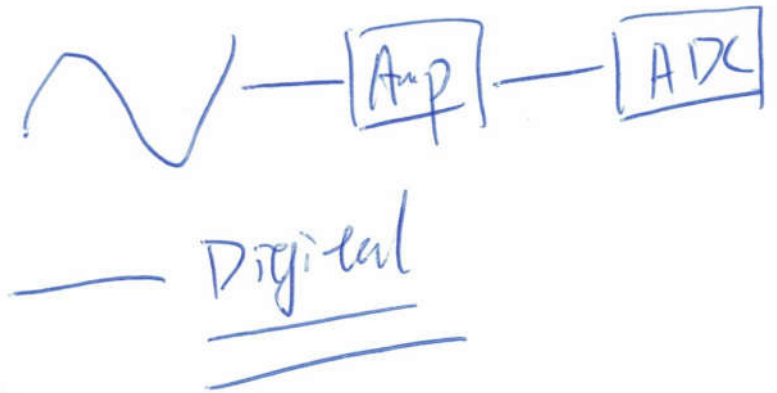
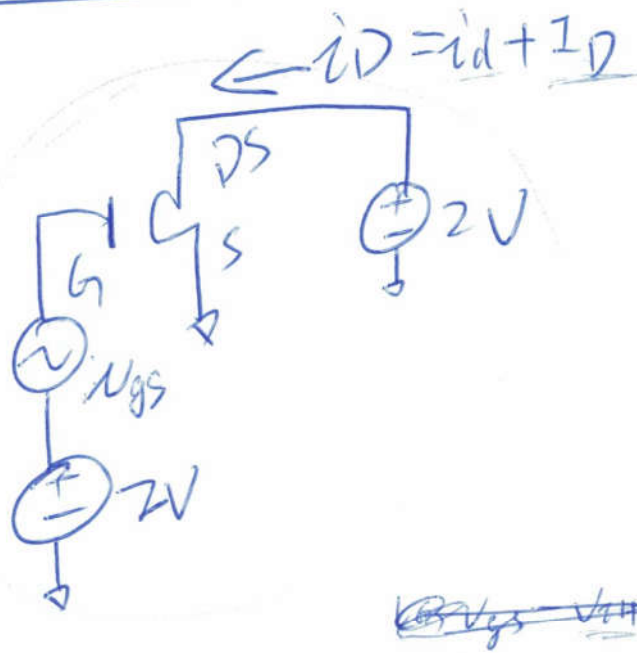


MOSFET Small Signal Models.



$$I_D = \frac{\beta_n}{2} (V_{GS} - V_{THN})^2$$

| | |
|----------|-------------------|
| v_{gs} | → Small signal AC |
| V_{GS} | → DC bias (DC) |
| v_{GS} | → AC+DC |
| i_d | → AC current |
| I_D | → DC current |
| i_D | → AC+DC |

$$i_D = I_D + i_d = \frac{\beta_n}{2} (\underbrace{V_{GS} + V_{GS}}_{V_{GS}} - V_{THN})^2$$

$$\beta_n = \frac{K_P W}{L}$$

$$\frac{\partial i_D}{\partial V_{GS}} = \beta_n (V_{GS} - V_{THN})$$

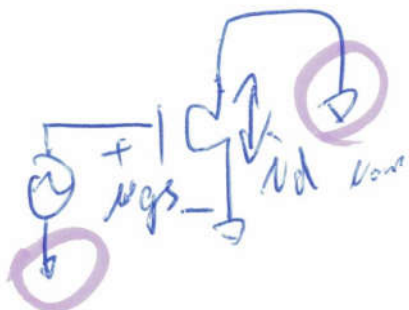
because $V_{GS} \rightarrow V_{GS}$

$$\frac{\partial i_D}{\partial V_{GS}} \approx \beta_n (V_{GS} - V_{THN}) = g_m \text{ Transconductance}$$

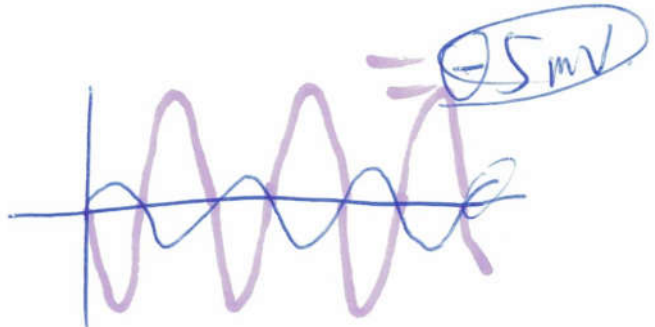
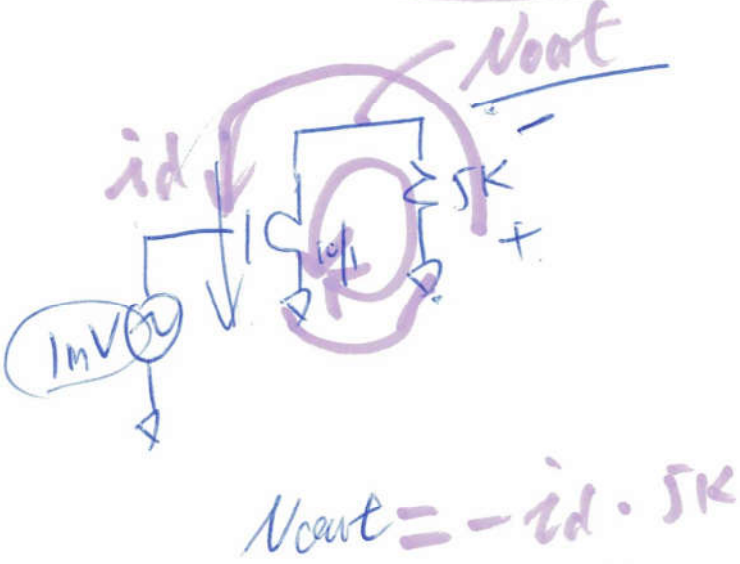
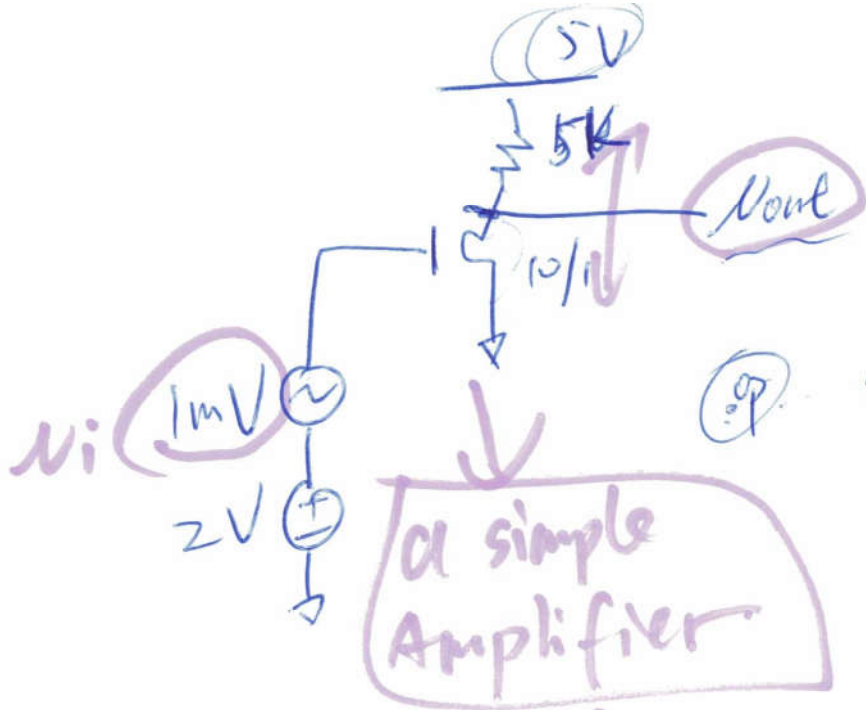
$$\sqrt{2} I_D = \frac{\beta_n}{2} (V_{GS} - V_{THN})^2$$

$$g_m = \sqrt{2 I_D \beta_n}$$

DC source is the AC ground



- step 1: get I_D : $I_D = \frac{\beta_n}{2} (V_{GS} - V_{THN})^2 = \dots$
- step 2: $g_m = \sqrt{2 I_D \beta_n} = \dots$
- step 3: $i_d = g_m v_{gs} = \dots$



$$K_p = 100 \mu\text{A}/\text{V}^2 \quad V_{out}?$$

start from the ^{DC} operating point

$$\text{step 1: } I_D = \frac{100 \mu\text{A}}{2} \cdot \frac{10}{1} (2 - \cancel{1})^2 \quad \underline{V_{th} = 1\text{V}}$$

$$= 500 \mu\text{A}$$

$$V_{out} = 5 - 5\text{k} \cdot 500 \mu\text{A} = 5 - 2500 \mu\text{V}$$

$$= 2.5\text{V}$$

$$V_{DS} \stackrel{?}{=} V_{GS} - V_{th}$$

$$= 2 - 1 = 1\text{V} \quad \text{Yes, saturation!}$$

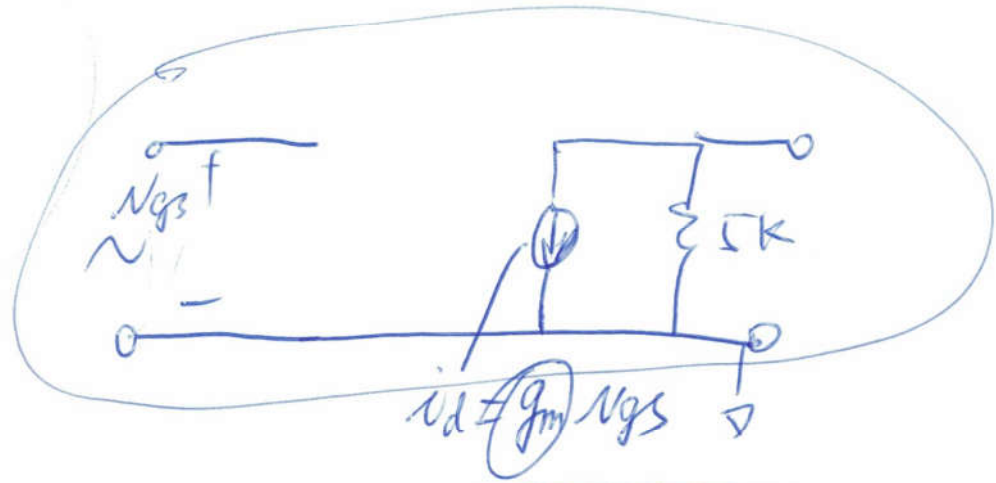
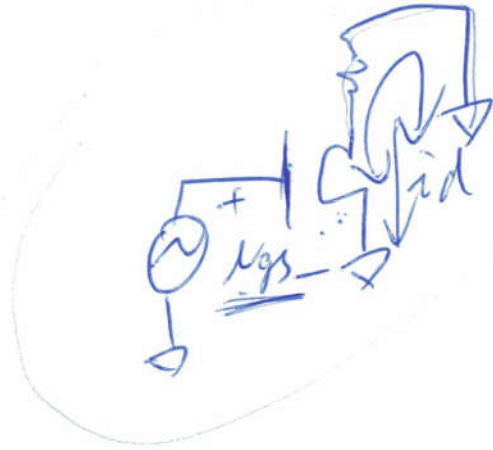
$$\text{step 2: } g_m = \sqrt{2 I_D \beta_n} = \sqrt{2 \cdot 500 \mu\text{A} \cdot \frac{100 \mu\text{A}}{1} \cdot \frac{10}{1}}$$

$$= \sqrt{1\text{m} \cdot 1\text{m}}$$

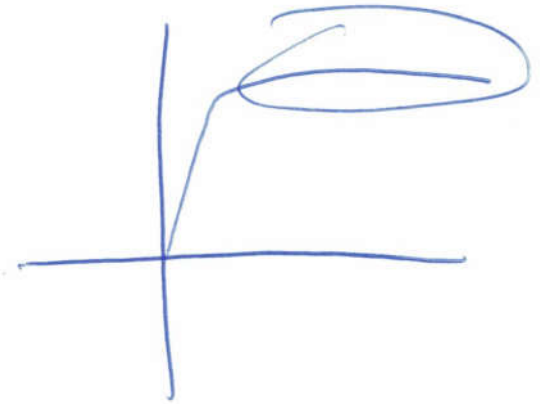
$$= 1\text{m A/V}$$

$$\text{step 3: } \underline{i_d} = g_m V_{gs} = 1\text{mA/V} \cdot 1\text{mV} = 1\mu\text{A}$$

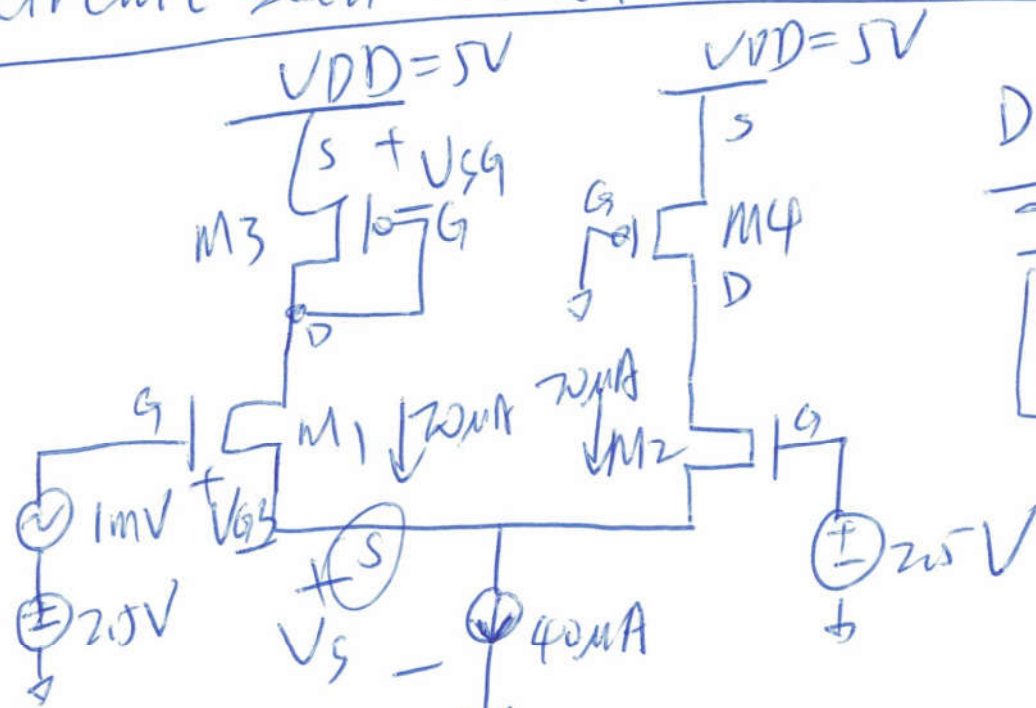
Small signal model



Voltage controlled
current source



Calculate the DC and AC voltages/currents for the circuit seen below:



Differential pair.

$$\begin{aligned} N_{MOS} &= 10/2 \\ P_{MOS} &= 30/2 \end{aligned}$$

$$\begin{aligned} K_{Pn} &= 120 \mu A/V \\ K_{Pp} &= 40 \mu A/V \end{aligned}$$

DC operating point

① M_1, M_2 have the same V_{GS} , the same $I_D = 40 \mu A / 2 = 20 \mu A$

② $V_{GS} = \sqrt{\frac{2I_D}{\mu_n C_{ox} W/L}} + V_{thn} = \sqrt{\frac{2 \cdot 20 \mu A}{120 \mu A \cdot \frac{10}{2}}} + 0.8 = 1.058$

$V_{G1} = 2.5V, V_{GS} = 1.058V, V_{S1} = V_{G1} - V_{GS} = 1.442V$

③ $V_{GS3} = \sqrt{\frac{2 \cdot I_D}{\mu_p C_{ox} W/L}} + V_{thp} = \sqrt{\frac{2 \cdot 20 \mu A}{40 \cdot \frac{30}{2}}} + 0.9 = 1.158V$

$V_{G3} = 5 - 1.158 = 3.842V = V_{D3} = V_{D1}$

CP3

